A comment on the order of the wetting transition at a solid–fluid interface

Cite as: J. Chem. Phys. **80**, 587 (1984); https://doi.org/10.1063/1.446404 Submitted: 22 April 1983 • Accepted: 12 September 1983 • Published Online: 31 August 1998

R. Evans and P. Tarazona

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also significantly smaller $(1.09 \pm 0.04 \text{ Hz})$ than the corresponding value in BH₄⁻, 81.00 Hz.⁸ The data in Table I also indicate that the primary isotope effect on ¹J(N,H) is very small, less than 0.2 Hz. A summary of isotope effects on spin-spin coupling constants has recently been given by Everett.⁹ Although it is possible to rationalize primary isotope effects on coupling constants, the interpretation of secondary isotope effects is more difficult.

We wish to thank NSERC for an operating grant to R.E.W. and a summer undergraduate research assistantship to J.O.F. This work was carried out at the Atlantic Regional NMR Center which was established through generous grants from NSERC and Dalhousie University.

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COMMENTS

A comment on the order of the wetting transition at a solid-fluid interface

R. Evans and P. Tarazona

H. H. Wills Physics Laboratory, University of Bristol, Bristol BS8 ITL, United Kingdom

(Received 22 April 1983; accepted 12 September 1983)

It is the purpose of this Comment to bring to attention some important discrepancies between the results obtained in two recent theoretical investigations of the order of the wetting transition at a solid-gas interface. Teletzke et al.¹ and the present authors² reported the results of independent analyses of this transition for certain models of solid-fluid interfaces. Both groups employed a mean-field free energy functional of the type introduced earlier by Sullivan³ and modeled the solid-fluid interactions by an external potential $u_{s}(x)$. Depending on the choice of potential functions, they found that the transition from partial to complete wetting, which occurs at a temperature T_{cw} below the bulk fluid critical temperature, could be a first-order surface phase transition, as predicted by Cahn⁴ and calculated by Ebner and Saam,⁵ or a second-order transition as found by Sullivan³ in his analysis of a special case of the free energy functional. The two groups agree that the order of the transition depends on the relative strengths and ranges of the attractive part of the solid-fluid and fluid-fluid potentials but they disagree on several specific details. In particular, when $u_{e}(x)$ was taken to be a Lennard-Jones 9-3 substrate potential and the attractive forces between fluid molecules were modeled by a Lennard-Jones 12-6 potential, our calculations^{2,6} showed that the transistion was always first order. This conclusion was supported by an approximate analysis² of the dependence of the interfacial free energy on the coverage which suggested that an infinitely thick wetting film should always be a metastable state of the system for $T < T_{cw}$ and, hence, the transition should always be first order for such a



FIG. 1. Adsorption isotherms calculated for a 9-3 substrate potential with $W_{9.3} = 7.0$ and d = 1.0. The solid curves are the results of Ref. 1 (Fig. 3) at four reduced temperatures T^* . The circles are our present results at $T^* = 0.21$. Note that the point at saturation $(n_b/n_{ext} = 1)$ corresponds to a metastable film. n_b is the density of the bulk gas. h is the film thickness in reduced units. The solid curves are consistent with a second-order transition at $T^*_{cw} = 0.24$ while the present results indicate a first-order transition slightly below 0.21.

model system. Teletzke *et al.*,¹ however, found from their calculations for a Lennard-Jones 9-3 substrate that the transition was not always first order but was second-order for certain choices of potential parameters. Given that the order of the wetting transition is not yet determined experimentally¹⁻³ and that the Lennard-Jones 9-3 substrate is quite a realistic and commonly used model, we believe it is important to attempt to establish with more certainty what is expected theoretically.

With this aim we repeated the calculations of Ref. 1 using the same "van der Waals integral theory," with identical potentials and parameters, as those authors. We consider first the results for the two cases in which solid-fluid and fluid-fluid potentials are modeled by exponential functions. For the first of these¹ ($W_{exp} = 0.7$ and d = 0.9) we calculate a second-order transition in agreement with Ref. 1. We find T_{cw}^* , the reduced transition temperature, is 0.251 which is quite close to their value 0.24. Teletzke et al. plot adsorption isotherms, and our results, for temperatures $T^* = 0.25$ and 0.23, lie very close to theirs (Fig. 1 of Ref. 1) for bulk densities \leq the saturated gas density. In the second exponential model $(W_{exp} = 0.5 \text{ and } d = 2.0)$, we find that the transition is first order, in agreement with Ref. 1, but occurs at $T_{cw}^* \leq 0.05$ rather than $T_{cov}^* = 0.11$, as given in Ref. 1. Moreover our results for the adsorption isotherms differ substantially from those plotted in Fig. 2 of Ref. 1. For example, at $T^* = 0.13$ and $n_b/n_{sat} = 0.9$ we find a (metastable) thin film and a (stable) thick film and calculate the thickness of the latter to be $h \sim 7.4$ while Teletzke *et al.* obtain $h \sim 5.6$.

Turning now to the results for the Lennard-Jones 9-3 solid-fluid potential we find more serious discrepancies. With parameters $W_{9-3} = 7.0$ and d = 1.0, Teletzke *et al.* calculated a second-order wetting transition at $T^*_{cw} = 0.24$ whereas we find a first-order transition at a temperature just below 0.21. In Fig. 1 we plot our results for the adsorption isotherm at $T^* = 0.21$ and compare with the isotherms of Ref. 1. We find that the film thickness remains finite $(h \sim 2.0)$



FIG. 2. The excess surface grand potential $\gamma^*(\Gamma)$ (in reduced units) at saturation as a function of the reduced coverage Γ^* for the model described in Fig. 1 at $T^* = 0.21$.

at saturation as is appropriate to a thin film. At the wetting transition this film coexists with the infinitely thick film while for the slightly higher temperature the thin film is slightly metastable.² By contrast, Teletzke et al.¹ find isotherms characteristic of a continuous, second-order transition. In order to demonstrate more explicitly the first-order character of our calculated transition we plot in Fig. 2 the surface excess grand potential per unit area $\gamma(\Gamma)$ as a function of the coverage Γ for $T^* = 0.21$ and $n_b/n_{sat} = 1$. This function⁷ has a minimum at a small value of reduced coverage $\Gamma^* = \Gamma l^2 \sim 1.4$ corresponding to the thin film with $h \sim 2.0$. This film is metastable since the value of $\gamma^* \equiv b l^2 \gamma / a$ at the minimum (-0.2525) is higher than the value corresponding to the minimum for infinite coverage which is $\gamma^*(\infty) \equiv \gamma_{s1}^* + \gamma_{1g}^* = -0.254$. Here γ_{s1} and γ_{1g} are the solid-liquid and liquid-gas surface tensions, respectively. The minima are separated by a pronounced maximum giving a metastability barrier² of height 0.0072. At the wetting transition $\gamma(\Gamma)$ is close to that shown in Fig. 2 but the values of the function at the minima are equal indicating coexistence of the two films. Such behavior signals unambiguously a firstorder phase transition.² Note, moreover, that since metastability barrier remains substantial at the wetting transition, the latter cannot be regarded as "weakly" first order in this case. We calculated the thick-thin film transition line, along which thick and thin film co-exist above T_{cw} , and found it terminated at a surface critical temperature $T_{cs} \simeq 0.24$. Since their transition is second order, Teletzke et al. do not obtain such a line.

The second 9-3 model sets $W_{9.3} = 12.0$ and d = 1.0. For this case we agree with Teletzke *et al.* that the transition is first order but we calculate a much lower transition temperature $T_{cw}^* \leq 0.08$ than their value of 0.14. Our results for T_{cs}^* is 0.14 whereas they find a value of 0.19 for the surface critical temperature. This has important repercussions for the adsorption isotherms. For example, the temperature $T^* = 0.16$ lies above T_{cs}^* in our calculations so the thickness of the film h grows monotonically with increasing n_b/n_{sat} , whereas the same temperature lies below T_{cs}^* in Ref. 1 so their isotherm exhibits a van der Waals loop at $T^* = 0.16$ (see Fig. 4 of Ref. 1).

We conclude from this comparison of results that one of the groups has made some numerical errors in their calculations. There are two important differences between the procedures which were employed. First, Teletzke et al. solved the relevant integral equation for the density profile of the fluid by converting it to a nonlinear differential equation which was then solved by the Galerkin finite-element method. Our method,² which was specifically designed to treat thick films, solves the integral equation by an iterative procedure. Secondly, our procedure^{2,7} for locating the wetting transition and determining its order is based on the calculation of $\gamma(\Gamma)$ and the subsequent determination of the minima of this function. This can be carried out very precisely (see Fig. 2). Teletzke et al. do not appear to calculate interfacial free energies but rely on investigation of the shape of the adsorption isotherms. The latter must be determined rather accurately for this procedure to be completely reliable. Indeed it necessitates the accurate calculation of density profiles of very thick films close to saturation. We suspect that Teletzke *et al.*'s numerical procedures might run into difficulties in this regime but this requires further investigation. Ideally, a third, independent, group should repeat the calculations and (hopefully!) resolve the issue. While we await the results of further studies, we are presently of the opinion that the wetting transition at a Lennard-Jones 9-3 substrate is always a first-order surface phase transition.⁸

This research was supported by the United Kingdom Science and Engineering Research Council.

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⁷The definition of and the procedure for calculating $\gamma(\Gamma)$ is described fully in Ref. 2.

⁸It is, of course, possible that choices of free-energy functional different from that employed here, or the incorporation of fluctuation corrections, could affect the order of the wetting transition, but we think that this is unlikely except, perhaps, when T_{cw} is very close to the bulk critical temperature. We believe that the argument given in Sec. II C of Ref. 2 lends strong support to this viewpoint. Recent calculations [M. P. Nightingale, W. F. Saam, and M. Schick (Phys. Rev. Lett. **51**, 1275 (1983)] for a solid-onsolid model, which include fluctuation corrections, also predict that longrange, inverse-power law potentials will always give rise to a first-order transition.

Reply to" A Comment on the order of the wetting transition at a solid-fluid interface"

R. E. Benner, Jr., G. F. Teletzke, L. E. Scriven, and H. T. Davis Department of Chemical Engineering and Materials Science. University of Minnesota, Minneapolis, Minnesota 55455

(Received 1 July 1983; accepted 12 September 1983)

We have independently repeated the calculations of Teletzke *et al.*¹ that are challenged by Evans and Tarazona.² The disputed results are adsorption isotherms given by van der Waals' integral theory with an exponential fluid potential and either an exponential fluid-solid potential or a Lennard-Jones 9-3 fluid-solid potential. The adsorption isotherms, calculated by Teletzke *et al.* by means of finite element analysis with a fixed basis, were in turn used to deduce the order of the wetting transition. In this note we choose an adaptive finite element procedure³ which controls solution error by concentrating basis functions in regions of high curvature of the density profile, i.e., in the solid-fluid interface and the fluid-fluid interface on the other side of the thick film.

We find a substantial departure from the results of Teletzke *et al.* as temperature is decreased and the film thickens. The qualitative difference from the results of Evans and Tarazona gave the prediction of a second-order transition when in fact first order prevails; this we traced to an error in implementing a standard approximation (cf. Appendix A of Ref. 4) to the equation $d^2u/dx^2 = G[u(x),x]$. The approximation consists of also expanding the forcing function G in the finite element basis $\{\psi_j\}: G = \Sigma G_j \psi_j(x)$. This was not done correctly in the code which generated the results of Sec. II of Ref. 1. In addition, at low temperatures the fluid interface narrows and its density profile sharpens, so that the fixed basis set employed by Teletzke *et al.* becomes inefficient, i.e., a large basis on a fine mesh must be used in calculating the thickening film accurately.

We adopt the notation used previously¹ and present the

correct results, first for the exponential fluid-solid potential

$$u_e(x^*) = -W_{\exp} \exp(-x^*/d),$$
 (1)

and then for the Lennard-Jones 9-3 potential

$$u_e(x^*) = W_{9-3} \left\{ \frac{1}{45} \left(\frac{d}{x^*} \right)^9 - \frac{1}{6} \left(\frac{d}{x^*} \right)^3 \right\}.$$
 (2)

When $W_{exp} = 0.7$ and d = 0.9, there is a second-order wetting transition at $T_{cw} = 0.25$, which is close to the critical



FIG. 1. Adsorption isotherms calculated from van der Waals integral theory with exponential fluid-solid potential and a choice of parameters giving a first-order transition. $T_{cs} = 0.20$, $T_{cw} < 0.11$ (cf. Fig. 2 of Ref. 1)

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